

### INCHANGE SEMICONDUCTOR

# isc N-Channel MOSFET Transistor

## **IRFP3207Z**

### FEATURES

- Drain Current –I\_D= 170A@ T\_C=25 $^\circ\!\!\!\mathrm{C}$
- Drain Source Voltage-: V<sub>DSS</sub>= 75V(Min)
- Static Drain-Source On-Resistance
- :  $R_{DS(on)}$  = 4.1m  $\Omega$  (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRIPTION

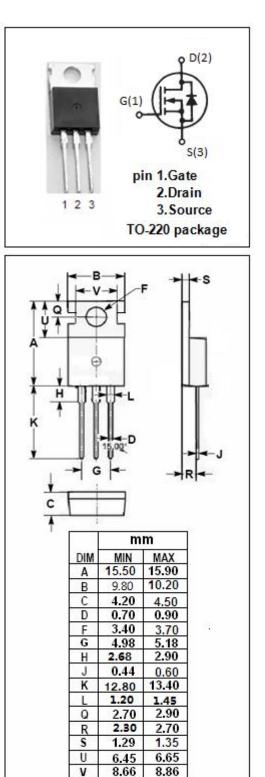
- High Speed Power Switching
- Hard Switched and High Frequency Circuits

SYMBOL	PARAMETER VALUE		UNIT
V <sub>DSS</sub>	Drain-Source Voltage	Voltage 75	
V <sub>GS</sub>	ate-Source Voltage-Continuous ±20		V
ID	Drain Current-Continuous 170		A
I <sub>DM</sub>	Drain Current-Single Pluse 670		A
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25℃	300	w
TJ	Max. Operating Junction Temperature	-55~175	°C
T <sub>stg</sub>	Storage Temperature	-55~175	°C

### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.5	°C/W





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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	75		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS}$ = $V_{GS}$ ; $I_D$ = 0.15mA	2.0	4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 75A		4.1	mΩ
lgss	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 75V; V <sub>GS</sub> = 0 V <sub>DS</sub> = 75V; V <sub>GS</sub> = 0@T <sub>J</sub> =125°C		20 250	μA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 75A; V <sub>GS</sub> = 0		1.3	V

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